

MOSFETs Silicon N-channel MOS (U-MOSIX-H)

XPJR6604PB

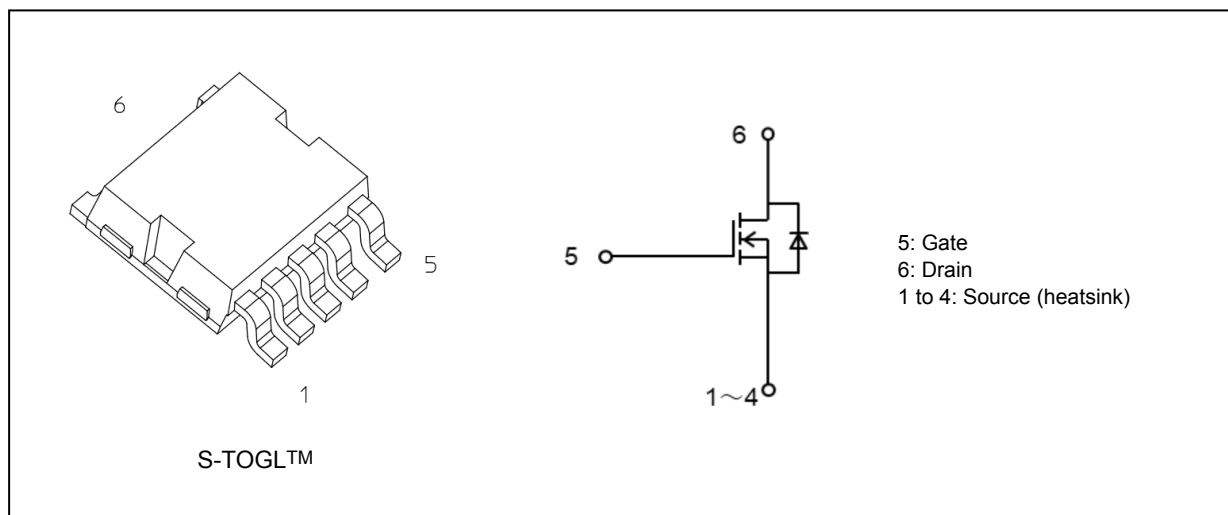
1. Applications

- Automotive
- Switching Voltage Regulators
- Motor Drivers
- DC-DC Converters

2. Features

- (1) AEC-Q101 qualified
- (2) Low drain-source on-resistance: $R_{DS(ON)} = 0.53 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (3) Low leakage current: $I_{DSS} = 10 \text{ }\mu\text{A}$ (max) ($V_{DS} = 40 \text{ V}$)
- (4) Enhancement mode: $V_{th} = 2.0 \text{ to } 3.0 \text{ V}$ ($V_{DS} = 10 \text{ V}$, $I_D = 1.0 \text{ mA}$)

3. Packaging and Internal Circuit Pin Assignment (Note)



Note: S-TOGL™ is a trademark of Toshiba Electronic Devices & Storage Corporation.

Start of commercial production

2023-05

4. Absolute Maximum Ratings (Note) ($T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Rating | Unit |
|--|-----------|------------|--------------------|
| Drain-source voltage | V_{DSS} | 40 | V |
| Gate-source voltage | V_{GSS} | ± 20 | |
| Drain current (DC) (Note 1) | I_D | 200 | A |
| Drain current (pulsed) (Note 1) | I_{DP} | 600 | |
| Power dissipation ($T_c = 25\text{ }^{\circ}\text{C}$) | P_D | 375 | W |
| Single-pulse avalanche energy (Note 2) | E_{AS} | 494 | mJ |
| Single-pulse avalanche current | I_{AS} | 100 | A |
| Channel temperature (Note 3) | T_{ch} | 175 | $^{\circ}\text{C}$ |
| Storage temperature (Note 3) | T_{stg} | -55 to 175 | $^{\circ}\text{C}$ |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|----------------|-----|-----------------------------|
| Channel-to-case thermal impedance ($T_c = 25\text{ }^{\circ}\text{C}$) | $Z_{th(ch-c)}$ | 0.4 | $^{\circ}\text{C}/\text{W}$ |

Note 1: Ensure that the channel temperature does not exceed $175\text{ }^{\circ}\text{C}$.

Note 2: $V_{DD} = 32\text{ V}$, $T_{ch} = 25\text{ }^{\circ}\text{C}$ (initial), $L = 38\text{ }\mu\text{H}$, $R_G = 25\text{ }\Omega$, $I_{AS} = 100\text{ A}$

Note 3: The definitions of the absolute maximum channel and storage temperatures are based on AEC-Q101.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---------------------------------|---------------|--|-----|------|---------|------------------|
| Gate leakage current | I_{GSS} | $V_{GS} = \pm 20\text{ V}$, $V_{DS} = 0\text{ V}$ | — | — | ± 1 | μA |
| Drain cut-off current | I_{DSS} | $V_{DS} = 40\text{ V}$, $V_{GS} = 0\text{ V}$ | — | — | 10 | |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $I_D = 10\text{ mA}$, $V_{GS} = 0\text{ V}$ | 40 | — | — | V |
| | $V_{(BR)DSX}$ | $I_D = 10\text{ mA}$, $V_{GS} = -20\text{ V}$ | 20 | — | — | |
| Gate threshold voltage (Note 4) | V_{th} | $V_{DS} = 10\text{ V}$, $I_D = 1.0\text{ mA}$ | 2.0 | — | 3.0 | |
| Drain-source on-resistance | $R_{DS(ON)}$ | $V_{GS} = 6\text{ V}$, $I_D = 100\text{ A}$ | — | 0.75 | 1.16 | $\text{m}\Omega$ |
| | | $V_{GS} = 10\text{ V}$, $I_D = 100\text{ A}$ | — | 0.53 | 0.66 | |

6.2. Dynamic Characteristics ($T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|-----------|---|-----|------|-------|-------------|
| Input capacitance | C_{iss} | $V_{DS} = 10\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 300\text{ kHz}$ | — | 8750 | 11380 | pF |
| Reverse transfer capacitance | C_{rss} | | — | 780 | 1100 | |
| Output capacitance | C_{oss} | | — | 5420 | — | |
| Gate resistance | r_g | | — | 2.9 | 5.8 | Ω |
| Switching time (rise time) | t_r | See Fig. 6.2.1 | — | 42 | — | ns |
| Switching time (turn-on time) | t_{on} | | — | 73 | — | |
| Switching time (fall time) | t_f | | — | 54 | — | |
| Switching time (turn-off time) | t_{off} | | — | 152 | — | |

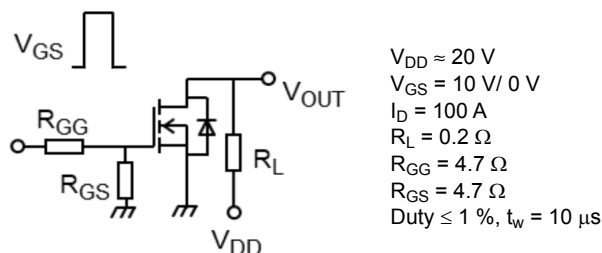


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|--|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Q_g | $V_{DD} \approx 32\text{ V}$, $V_{GS} = 10\text{ V}$, $I_D = 200\text{ A}$ | — | 128 | — | nC |
| Gate-source charge 1 | Q_{gs1} | | — | 43 | — | |
| Gate-drain charge | Q_{gd} | | — | 29 | — | |

6.4. Source-Drain Characteristics ($T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|---|-----|------|------|------|
| Reverse drain current (DC) (Note 5) | I_{DR} | — | — | — | 200 | A |
| Reverse drain current (pulsed) (Note 5) | I_{DRP} | — | — | — | 600 | |
| Diode forward voltage | V_{DSF} | $I_{DR} = 200\text{ A}$, $V_{GS} = 0\text{ V}$ | — | — | -1.2 | V |
| Reverse recovery time | t_{rr} | $I_{DR} = 200\text{ A}$, $V_{GS} = 0\text{ V}$ $-di_{DR}/dt = 100\text{ A}/\mu\text{s}$ | — | 84 | — | ns |
| Reverse recovery charge | Q_{rr} | | — | 151 | — | nC |

Note 5: Ensure that the channel temperature does not exceed $175\text{ }^{\circ}\text{C}$.

7. Marking

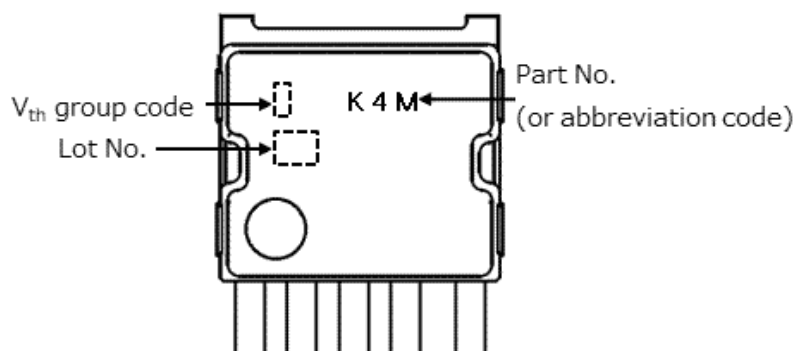


Fig. 7.1 Marking

Note 4: If requested, V_{th} grouping is possible for each reel. (V_{th} width is 0.4 V)

However, we do not accept specifications in specific groups.

If there is no request, the group-free reel will be applied. (V_{th} width is 1.0 V, no V_{th} group code is printed on marking)

8. Characteristics Curves (Note)

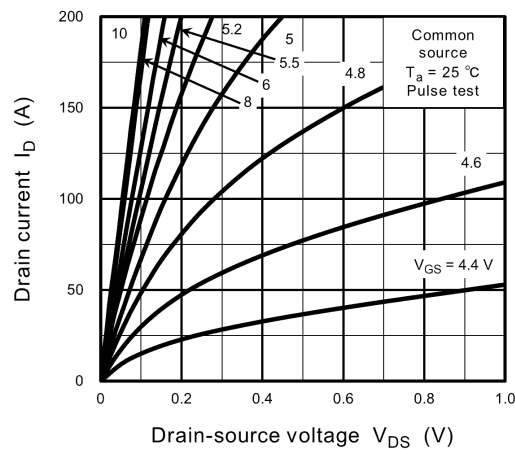


Fig. 8.1 $I_D - V_{DS}$

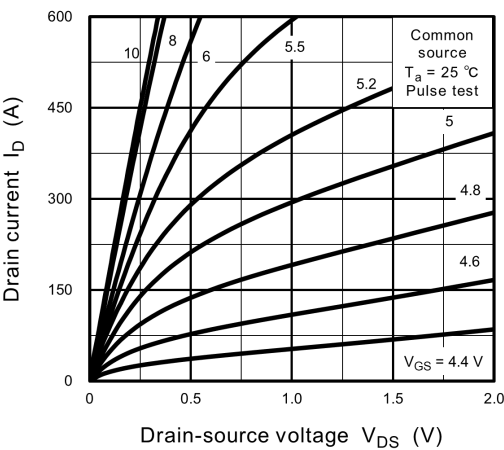


Fig. 8.2 $I_D - V_{DS}$

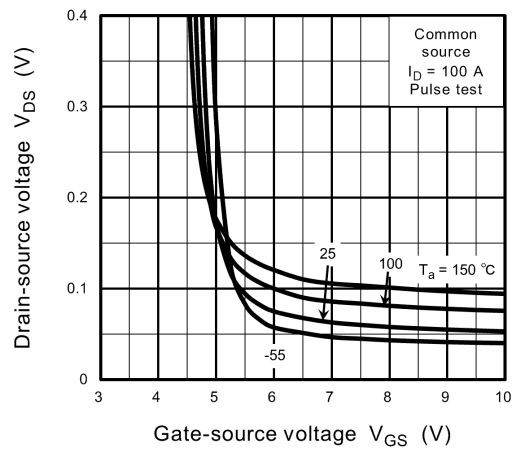


Fig. 8.3 $V_{DS} - V_{GS}$

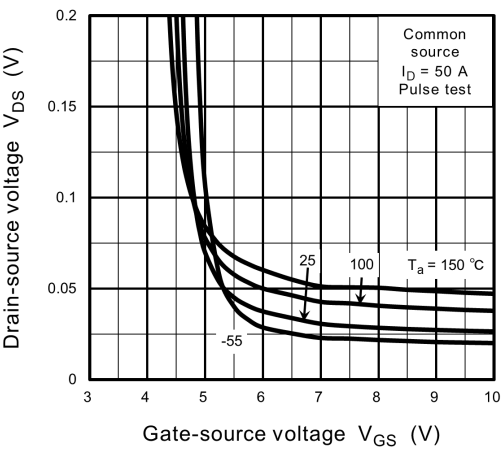


Fig. 8.4 $V_{DS} - V_{GS}$

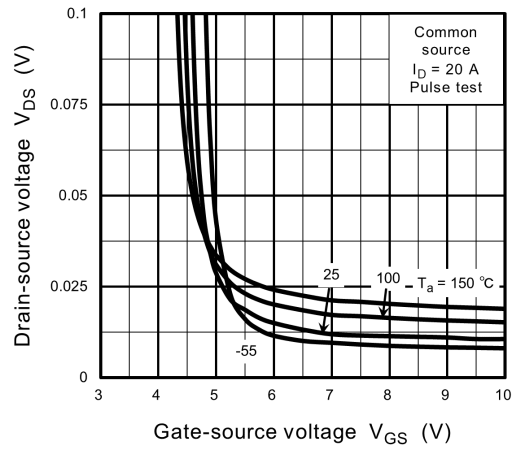


Fig. 8.5 $V_{DS} - V_{GS}$

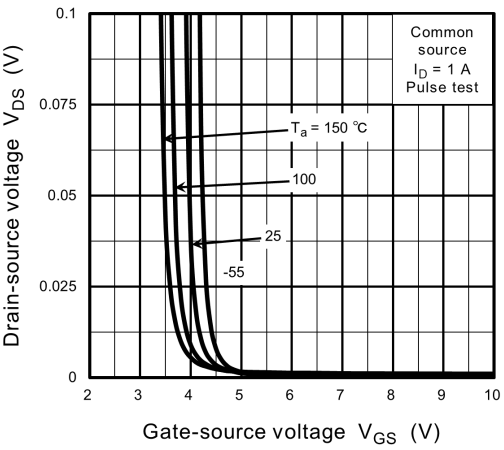


Fig. 8.6 $V_{DS} - V_{GS}$

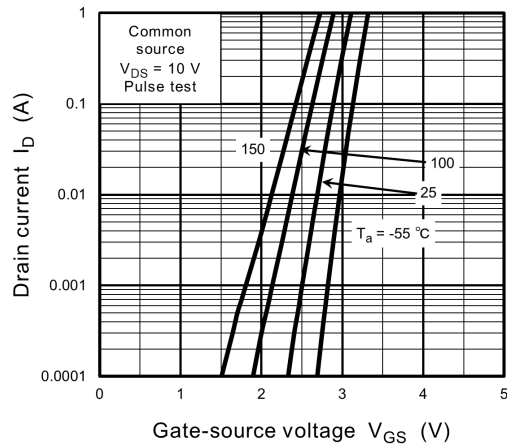


Fig. 8.7 $I_D - V_{GS}$

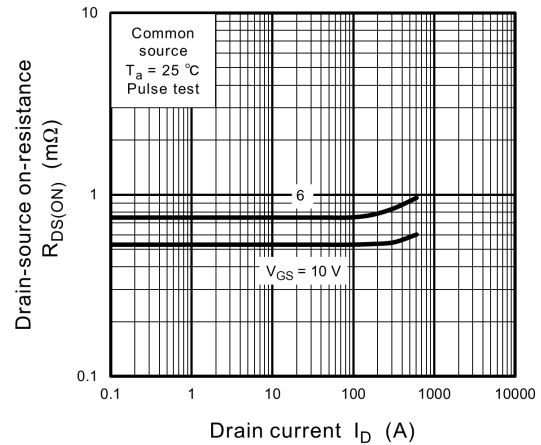


Fig. 8.8 $R_{DS(ON)} - I_D$

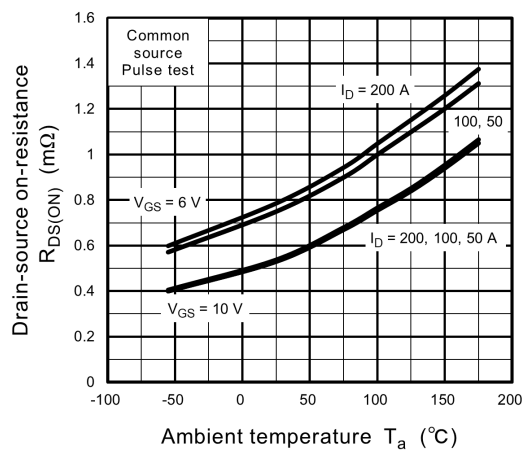


Fig. 8.9 $R_{DS(ON)} - T_a$

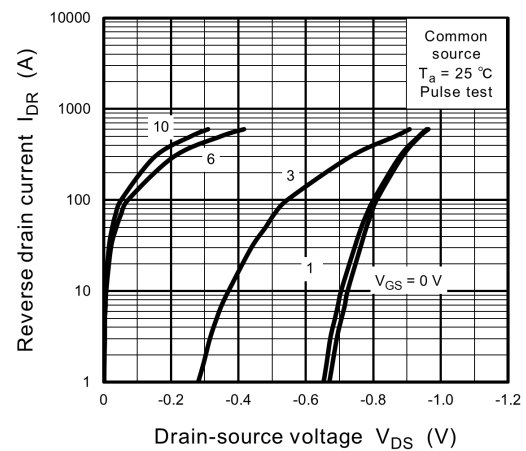


Fig. 8.10 $I_{DR} - V_{DS}$

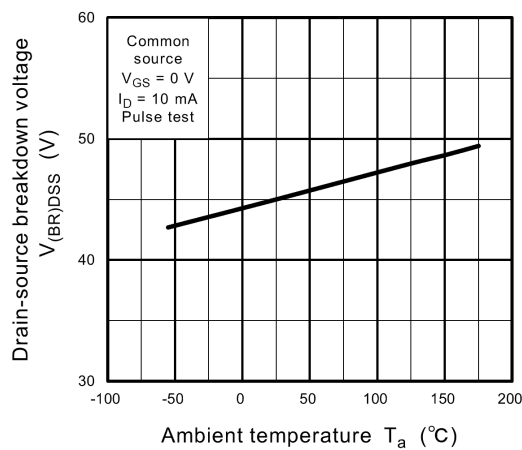


Fig. 8.11 $V_{(BR)DSS} - T_a$

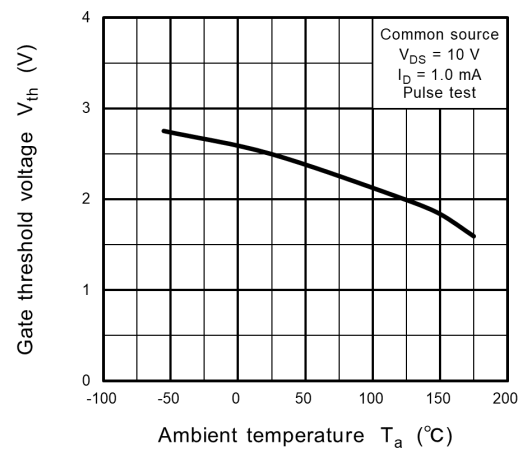


Fig. 8.12 $V_{th} - T_a$

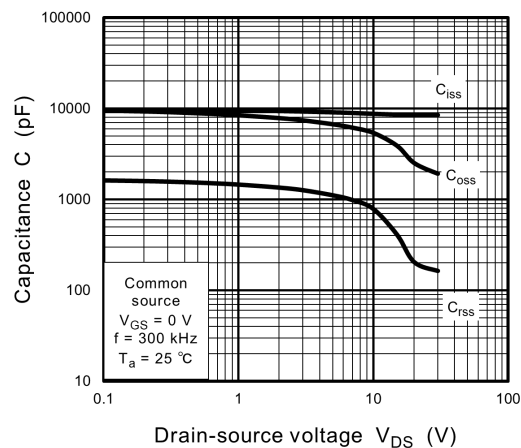


Fig. 8.13 Capacitance - V_{DS}

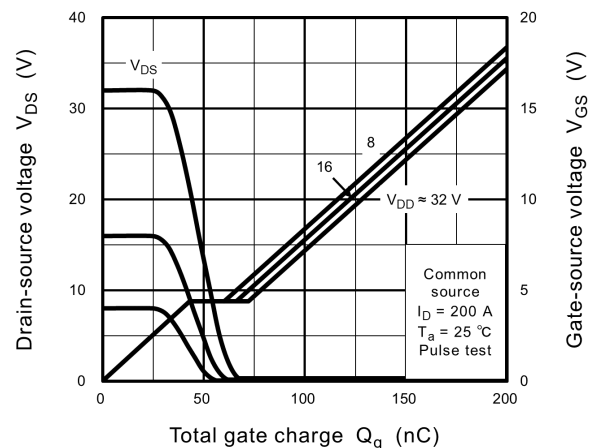


Fig. 8.14 Dynamic Input/Output Characteristics

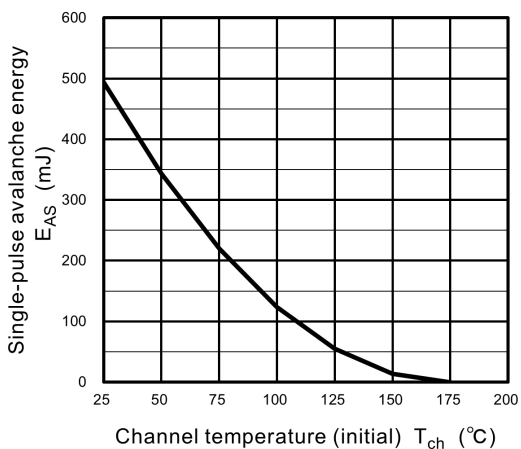


Fig. 8.15 E_{AS} - T_{ch} (Guaranteed Maximum)

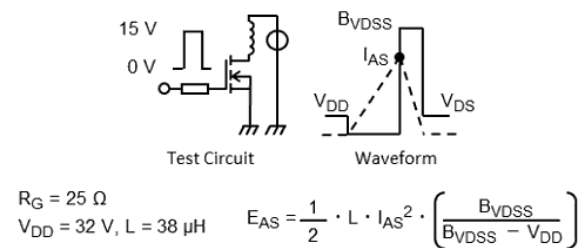


Fig. 8.16 Test Circuit/Waveform

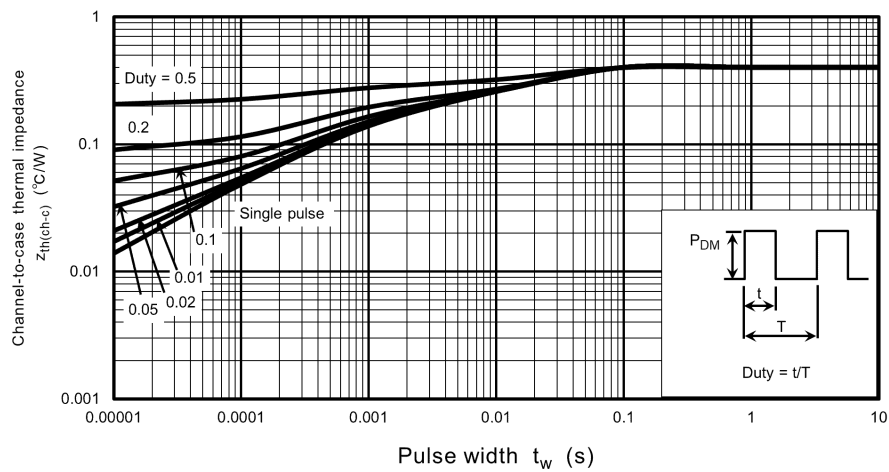


Fig. 8.17 $Z_{th(ch-c)} - t_w$
(Guaranteed Maximum)

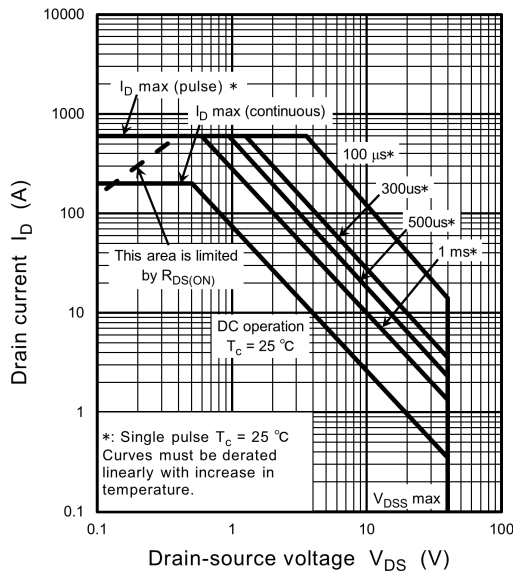


Fig. 8.18 Safe Operating Area
(Guaranteed Maximum)

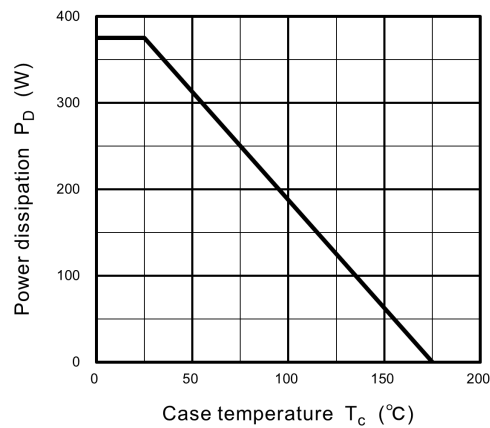
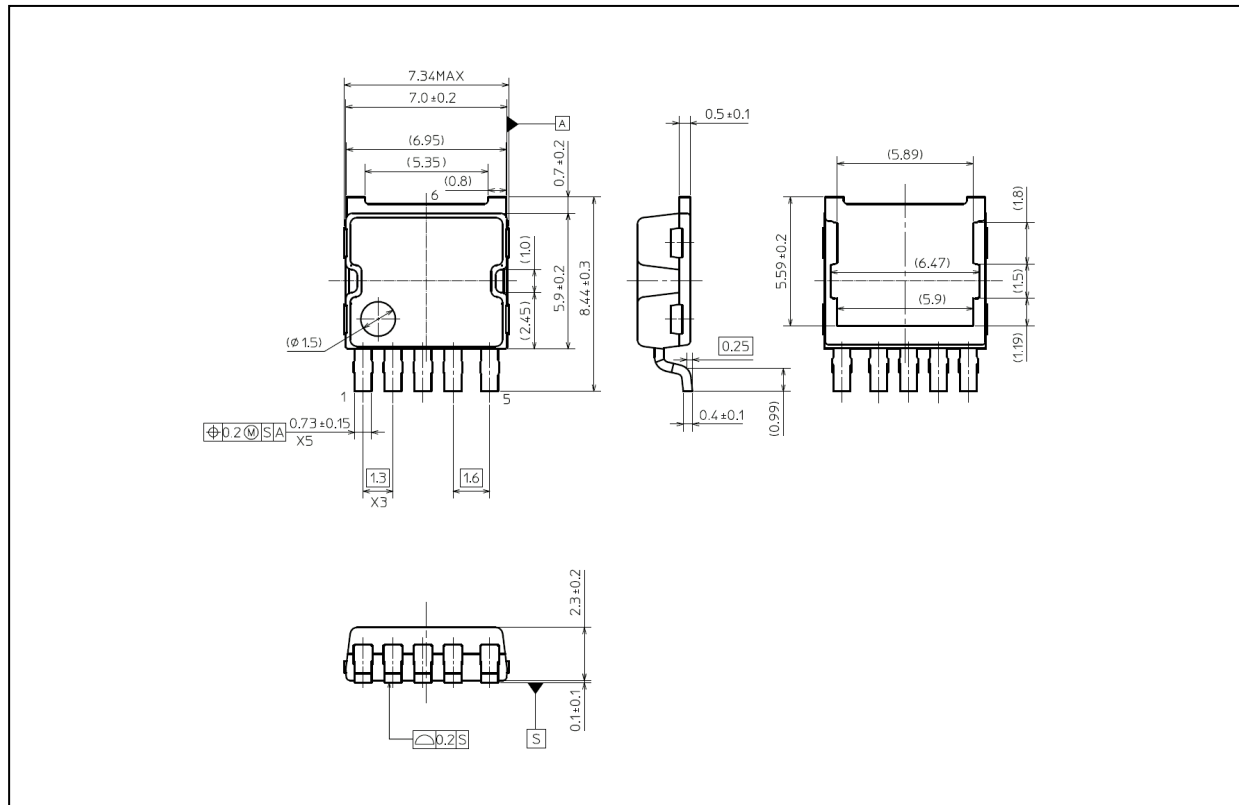


Fig. 8.19 $P_D - T_c$
(Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.395 g (typ.)

| Package Name(s) |
|-------------------|
| TOSHIBA: 2-7P1A |
| Nickname: S-TOGL™ |

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